

N-Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY

| V _{DS} (V) | R _{DS(on)} (mΩ)(Typ.) | I _D (A) ^a | Q _g (Typ.) |
|---------------------|--------------------------------|---------------------------------|-----------------------|
| 100 | 1.3 at V _{GS} = 10 V | 324 | 140 nC |

FEATURES

- DT-SGT Power MOSFET
- 100 % R_g and UIS Tested
- Low On-Resistance
- Excellent FoM (figure of merit)



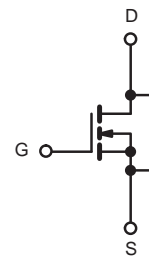
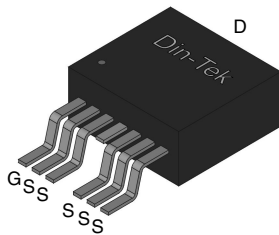
RoHS
COMPLIANT

APPLICATIONS

- DC/DC in Telecoms and Industrial
- Synchronous Rectification in SMPS
- Hard Switching and High Speed Circuit

TO-263-6L Pin Configuration

Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNIT |
|---|-----------------------------------|-------------------------|------|
| Drain-Source Voltage | V _{DS} | 100 | V |
| Gate-Source Voltage | V _{GS} | ± 20 | |
| Continuous Drain Current (T _J = 175 °C) ^a | I _D | T _C = 25 °C | 324 |
| | | T _C = 100 °C | 229 |
| Pulsed Drain Current ^b | I _{DM} | 1295 | A |
| Single Avalanche Energy | E _{AS} | 2016 | mJ |
| Maximum Power Dissipation ^c | P _D | T _C = 25 °C | 326 |
| | | T _C = 100 °C | 163 |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | -55 to+175 | °C |

THERMAL RESISTANCE RATINGS

| PARAMETER | SYMBOL | LIMIT | UNIT |
|--|-------------------|-------|------|
| Junction-to-Ambient (PCB Mount) ^d | R _{thJA} | 38 | °C/W |
| Junction-to-Case (Drain) | R _{thJC} | 0.46 | |

Notes

- Calculated continuous current based on maximum allowable junction temperature.
- Repetitive rating; pulse width limited by max. junction temperature.
- P_D is based on max. junction temperature, using junction-case thermal resistance.
- The value of R_{thJA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with T_a=25 °C.

| SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | |
|---|--------------|--|------|------|-----------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$ | 100 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$ | 2.0 | - | 4.0 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$ | - | - | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$ | - | - | 1 | μA |
| | | $V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}, T_J = 125\text{ }^\circ\text{C}$ | - | - | 100 | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{DS} \geq 5\text{ V}, V_{GS} = 10\text{ V}$ | 324 | - | - | A |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = 10\text{ V}, I_D = 20\text{ A}$ | - | 1.3 | 1.6 | m Ω |
| Forward Transconductance ^a | g_{fs} | $V_{DS} = 5\text{ V}, I_D = 20\text{ A}$ | - | 78 | - | S |
| Dynamic ^b | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0\text{ V}, V_{DS} = 50\text{ V}, f = 1\text{ MHz}$ | - | 9660 | - | pF |
| Output Capacitance | C_{oss} | | - | 3476 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 48 | - | |
| Total Gate Charge ^c | Q_g | $V_{DS} = 50\text{ V}, V_{GS} = 10\text{ V}, I_D = 20\text{ A}$ | - | 140 | - | nC |
| Gate-Source Charge ^c | Q_{gs} | | - | 38 | - | |
| Gate-Drain Charge ^c | Q_{gd} | | - | 27 | - | |
| Gate Resistance | R_g | $f = 1\text{ MHz}$ | - | 2.0 | - | Ω |
| Turn-On Delay Time ^c | $t_{d(on)}$ | $V_{DD} = 50\text{ V}, I_D = 20\text{ A}, R_g = 3\text{ }\Omega$ $V_{GS} = 10\text{ V}$ | - | 25 | - | ns |
| Rise Time ^c | t_r | | - | 42 | - | |
| Turn-Off Delay Time ^c | $t_{d(off)}$ | | - | 87 | - | |
| Fall Time ^c | t_f | | - | 63 | - | |
| Drain-Source Body Diode Ratings and Characteristics ^b ($T_J = 25\text{ }^\circ\text{C}$) | | | | | | |
| Continuous Source-Drain Diode Current | I_S | $T_C = 25\text{ }^\circ\text{C}$ | - | - | 324 | A |
| Pulsed Current | I_{SM} | | - | - | 1295 | A |
| Forward Voltage ^a | V_{SD} | $I_F = 2\text{ A}, V_{GS} = 0\text{ V}$ | - | 0.7 | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $I_F = 20\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$ | - | 105 | - | ns |
| Reverse Recovery Charge | Q_{rr} | | - | 394 | - | nC |

Notes

- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

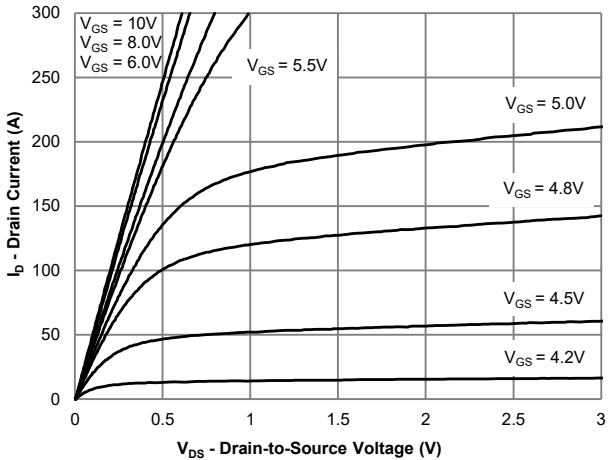


Figure 1: Output Characteristics

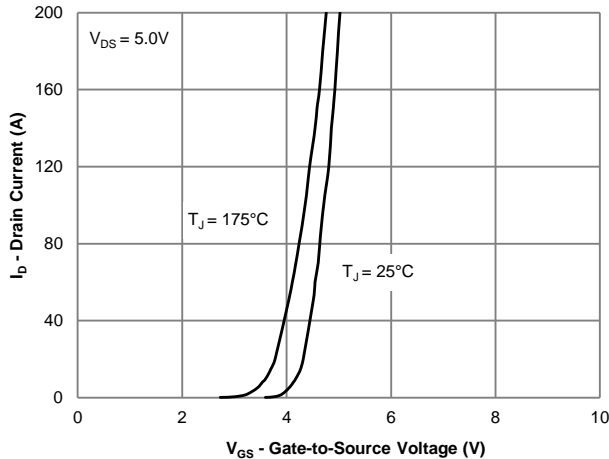


Figure 2: Transfer Characteristics

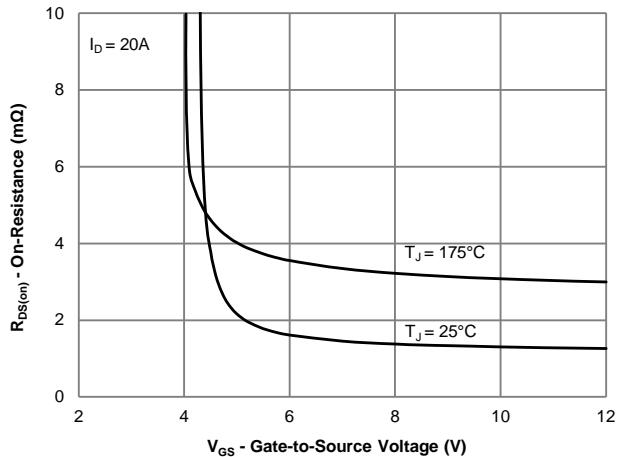


Figure 3: On-Resistance vs. Gate-Source Voltage

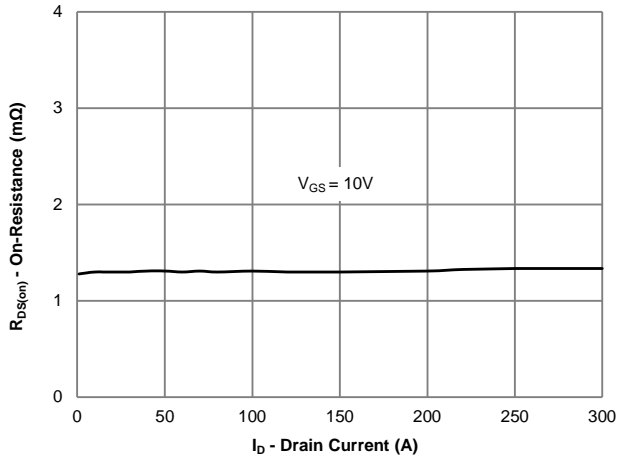


Figure 4: On-Resistance vs. Drain Current

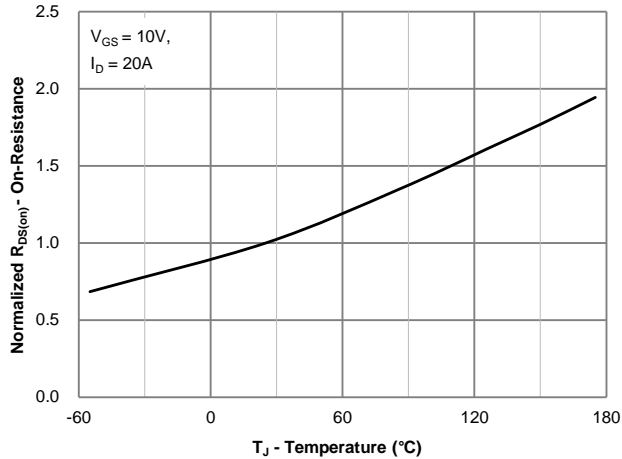


Figure 5: On-Resistance vs. Junction Temperature

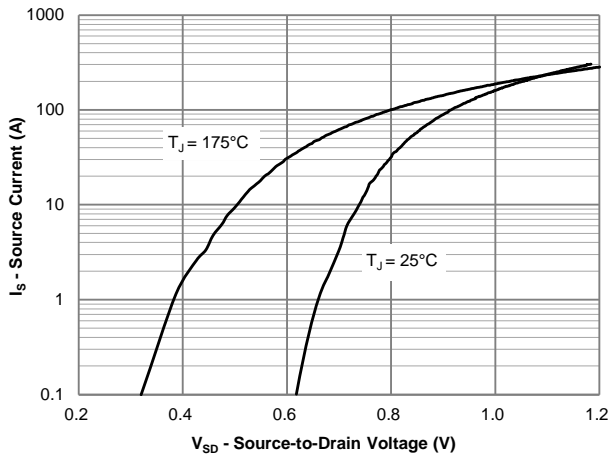


Figure 6: Source-Drain Diode Forward Voltage

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

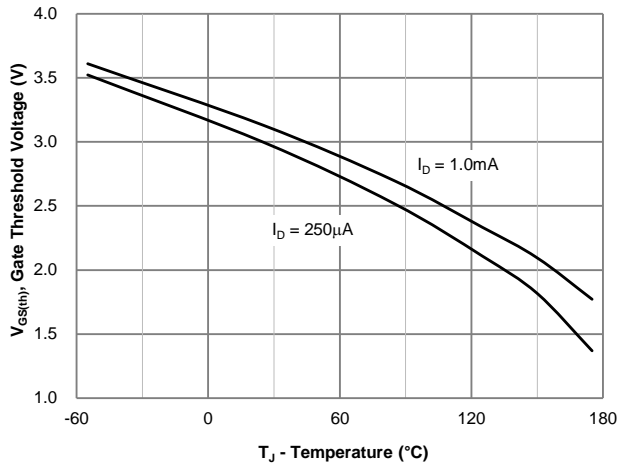


Figure 7: Gate Threshold Variation vs. Junction Temperature

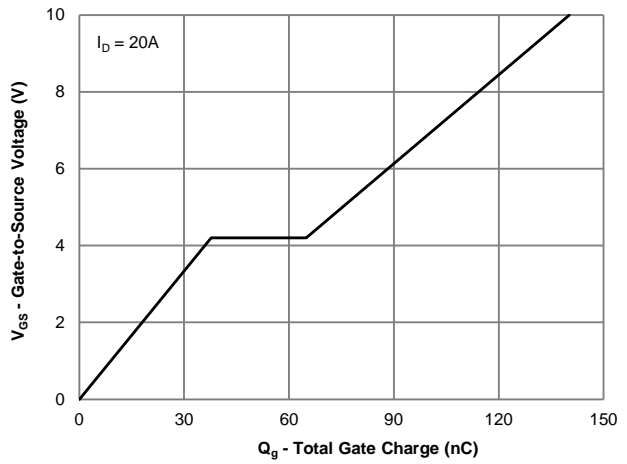


Figure 8: Gate Charge Characteristics

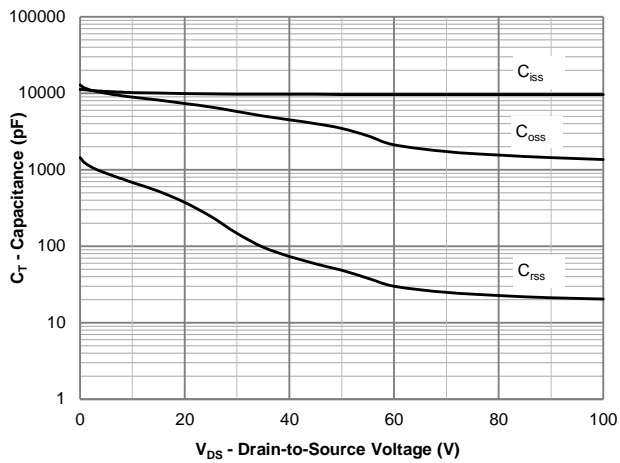


Figure 9: Capacitance Characteristics

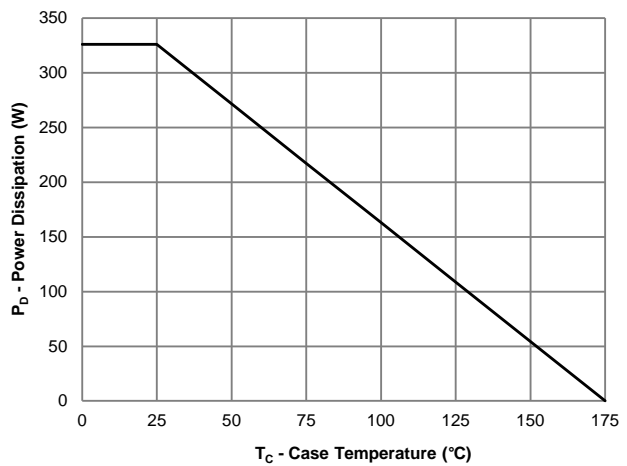


Figure 10: Power Derating

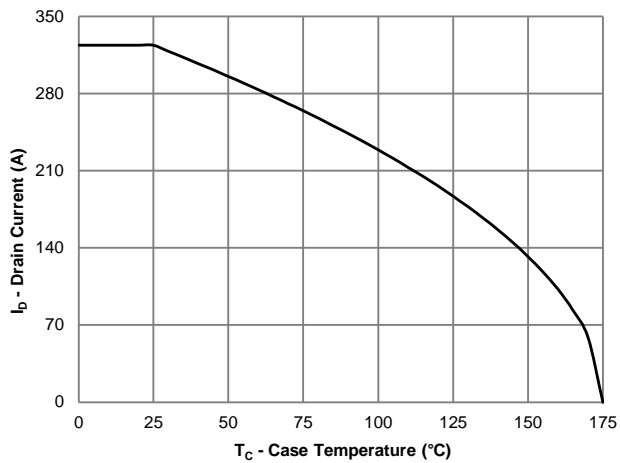


Figure 11: Current Derating

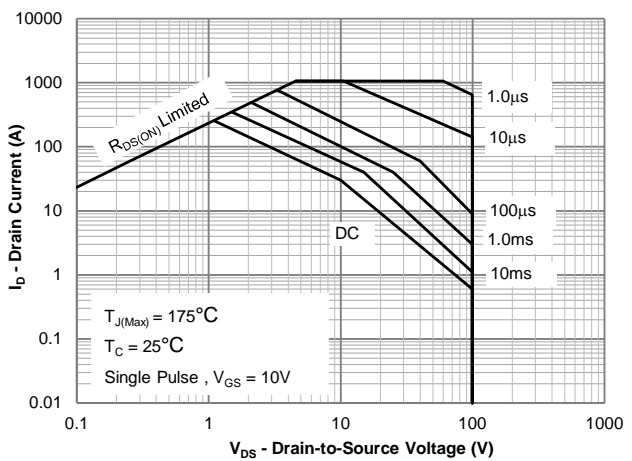


Figure 12: Safe Operating Area

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

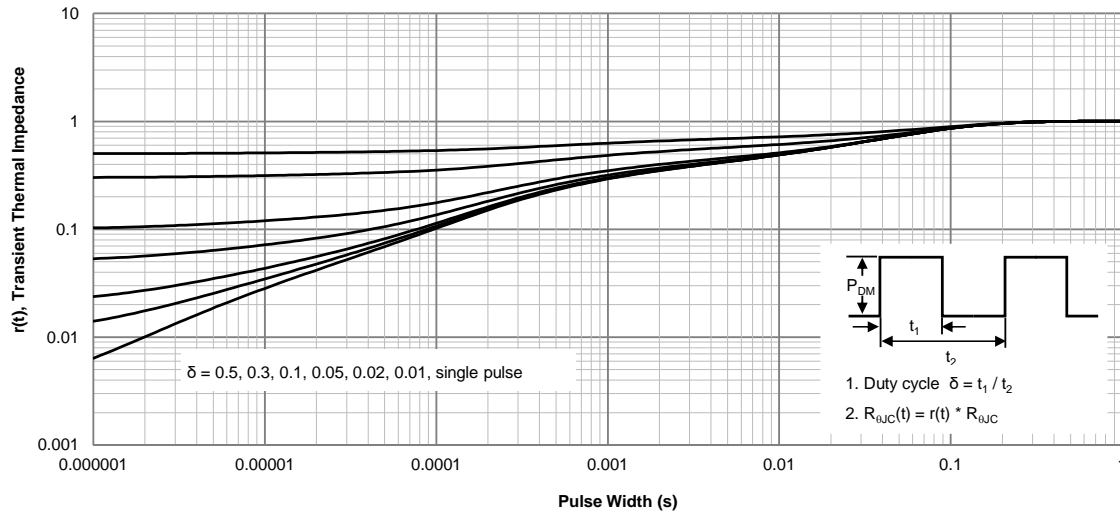
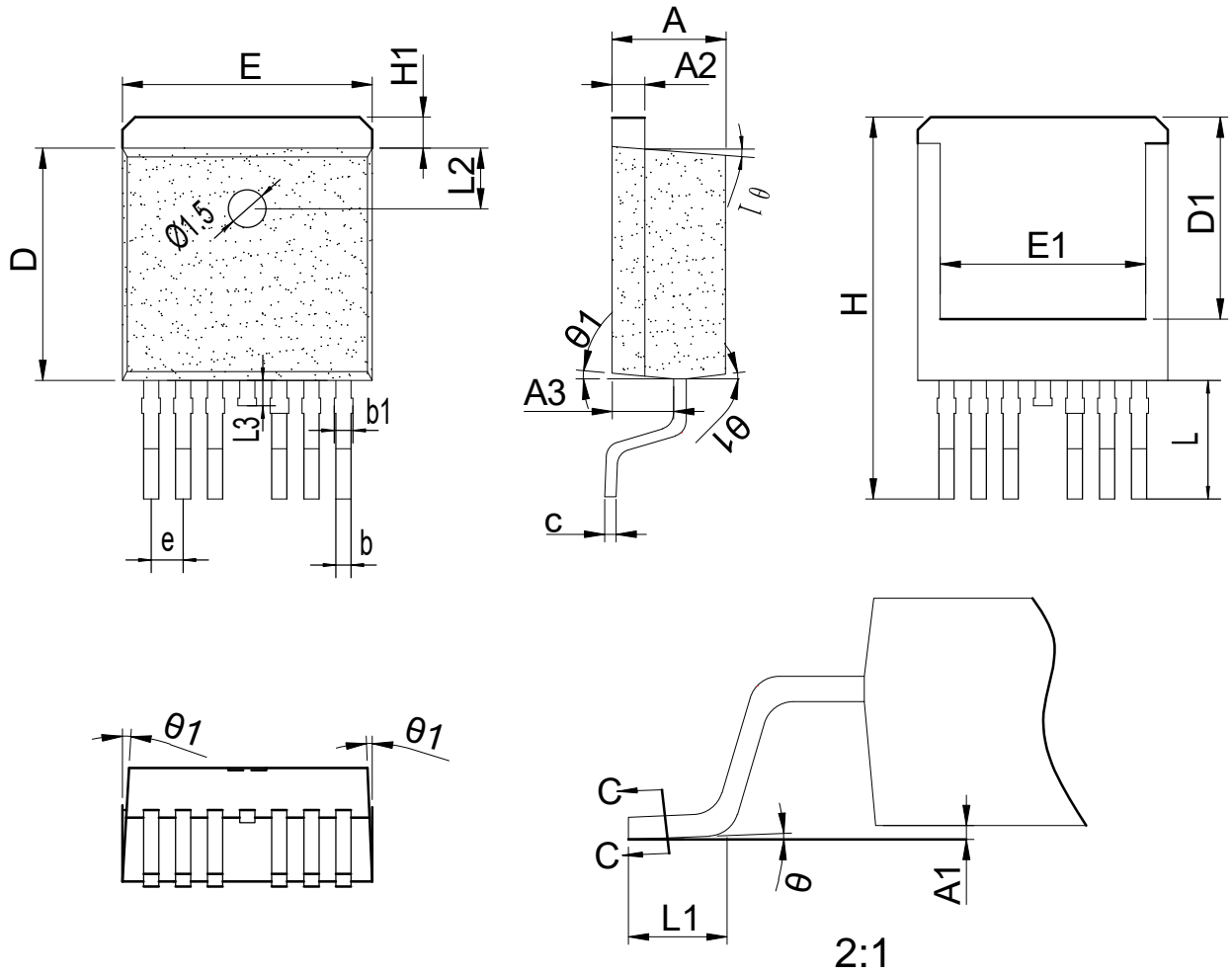


Figure 13: Normalized Maximum Transient Thermal Impedance

TO-263-6L PACKAGE OUTLINE



Unit:mm

| SYMBOL | MIN | TYP | MAX | SYMBOL | MIN | TYP | MAX |
|--------|------|-------|-------|--------|-------|-------|-------|
| A | 4.30 | 4.40 | 4.50 | E1 | 8.40 | 8.60 | 8.80 |
| A1 | 0.00 | 0.10 | 0.20 | e | 1.25 | 1.27 | 1.29 |
| A2 | 1.22 | 1.27 | 1.32 | H | 14.85 | 15.00 | 15.15 |
| A3 | 2.30 | 2.40 | 2.50 | H1 | 0.90 | 1.00 | 1.10 |
| b | 0.50 | 0.60 | 0.70 | L | 4.50 | 4.70 | 4.90 |
| b1 | 0.60 | 0.75 | 0.90 | L1 | 2.40 | 2.70 | 3.00 |
| c | 0.45 | 0.50 | 0.55 | L2 | 2.20 | 2.30 | 2.40 |
| D | 9.10 | 9.20 | 9.30 | L3 | 0.85 | 1.00 | 1.15 |
| D1 | 7.80 | 8.00 | 8.20 | θ | 0° | 2.5° | 8° |
| E | 9.80 | 10.00 | 10.20 | θ1 | 5° | 7° | 9° |

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